

**FEATURES**

- \* 2.0 inch (50.8 mm) MATRIX HEIGHT.
- \* LOW POWER REQUIREMENT.
- \* EXCELLENT CHARACTERS APPEARANCE..
- \* HIGH BRIGHTNESS & HIGH CONTRAST.
- \* 5×7 ARRAY WITH X-Y SELECT.
- \* HIGH BRIGHTNESS & HIGH CONTRAST.
- \* SOLID STATE RELIABILITY.

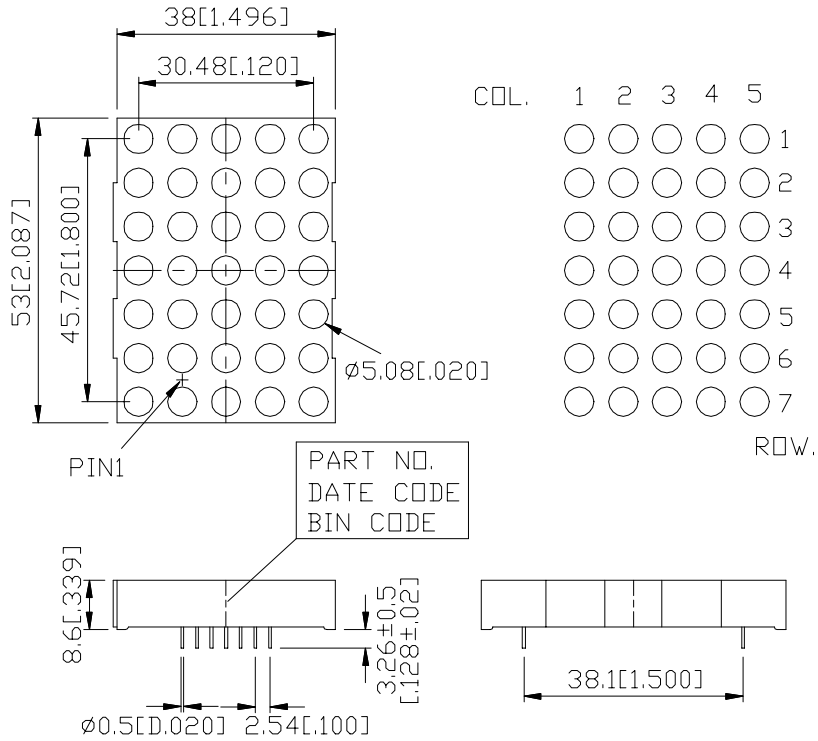
**DESCRIPTION**

The LTP-2157AKY is a 2.0 inch (50.8 mm) matrix height 5×7 dot matrix display. This device utilizes AllnGaP Amber Yellow LED chips, which are made from AllnGaP on a non-transparent GaAs substrate, and has a gray face and white dot color.

**DEVICE**

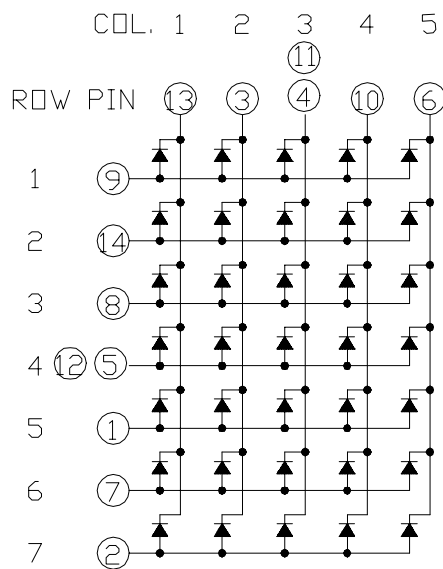
<b>PART NO.</b>	<b>DESCRIPTION</b>
AllnGaP Amber Yellow	CATHODE COLUMN
LTP-2157AKY	ANODE ROW

## PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are  $\pm 0.25$  mm (0.01") unless otherwise noted.

## INTERNAL CIRCUIT DIAGRAM



**PIN CONNECTION**

<b>No.</b>	<b>CONNECTION</b>
1	ANODE ROW 5
2	ANODE ROW 7
3	CATHODE COLUMN 2
4	CATHODE COLUMN 3*1
5	ANODE ROW 4*2
6	CATHODE COLUMN 5
7	ANODE ROW 6
8	ANODE ROW 3
9	ANODE ROW 1
10	CATHODE COLUMN 4
11	CATHODE COLUMN 3*1
12	ANODE ROW 4*2
13	CATHODE COLUMN 1
14	ANODE ROW 2

NOTES : 1. Pin 4 & 11 are internally connected.

2. Pin 5 & 12 are internally connected.

**ABSOLUTE MAXIMUM RATING AT Ta=25°C**

PARAMETER	MAXIMUM RATING	UNIT
Average Power Dissipation Per Dot	35	mW
Peak Forward Current Per Dot	60	mA
Average Forward Current Per Dot	13	mA
Derating Linear From 25°C Per Dot	0.17	mA/°C
Reverse Voltage Per Dot	5	V
Operating Temperature Range	-35°C to +85°C	
Storage Temperature Range	-35°C to +85°C	
Solder Temperature: max 260°C for max 3sec at 1.6mm[1/16inch] below seating plane.		

**ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C**

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I <sub>v</sub>	2100	3600		μcd	I <sub>p</sub> =32mA 1/16Duty
Peak Emission Wavelength	λ <sub>p</sub>		595		nm	I <sub>F</sub> =20mA
Spectral Line Half-Width	Δλ		15		nm	I <sub>F</sub> =20mA
Dominant Wavelength	λ <sub>d</sub>		592		nm	I <sub>F</sub> =20mA
Forward Voltage Per Segment	V <sub>F</sub>		2.05	2.6	V	I <sub>F</sub> =20mA
Reverse Current any Dot	I <sub>R</sub>			100	μA	V <sub>R</sub> =5V
Luminous Intensity Matching Ratio	I <sub>v</sub> -m			2:1		I <sub>F</sub> =2mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

**TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES**

(25°C Ambient Temperature Unless Otherwise Noted)

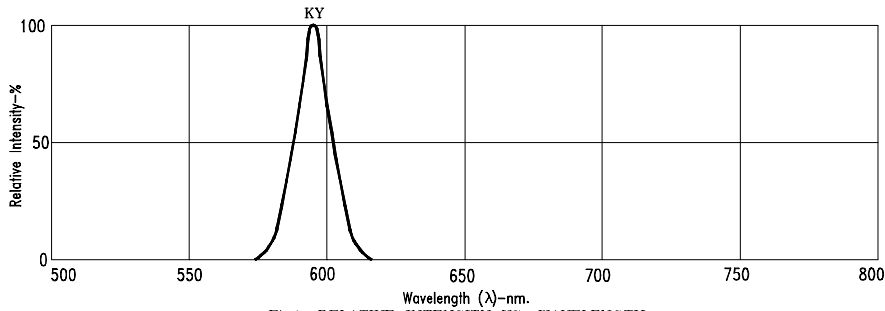


Fig1. RELATIVE INTENSITY VS. WAVELENGTH

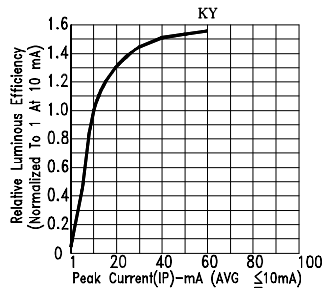


Fig2. RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT

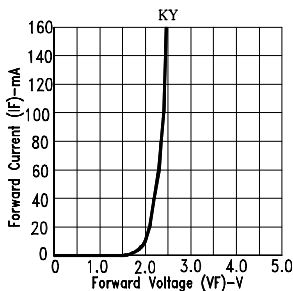


Fig3. FORWARD CURRENT VS. FORWARD VOLTAGE

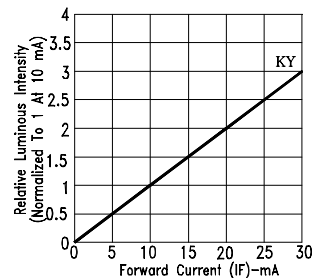


Fig4. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

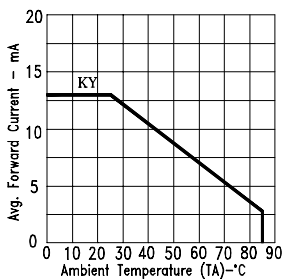


Fig5. MAX AVERAGE FORWARD CURRENT VS. AMBIENT TEMPERATURE.

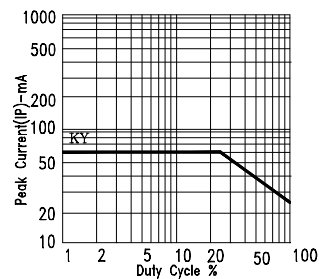


Fig6. MAX. PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE 1KHz)

NOTE: KY=AlInGaP AMBER YELLOW